

Dual N-Channel Power Trench® MOSFET 40V, 98A, 2.6mΩ

Manufacturers	ON Semiconductor, LLC
Package/Case	PQFN-12
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for FDMD8240L or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

This device includes two 40V N-Channel MOSFETs in a dual Power (3.3 mm X 5 mm) package. HS source and LS Drain are internally connected for half/full bridge, low source inductance package, low rDS(on) / Qg FOM silicon.

Features

Termination is Lead-free and RoHS Compliant

Application

ONSEMI

Related Products



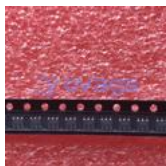
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